NSN 5961-01-189-0870



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-189-0870 **Inclosure Material:** Metal **Overall Length:** 1.252 inches **Overall Height:** 0.340 inches **Overall Width:** 0.700 inches **End Application:** Aircraft, eagle f-15 **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 drain to source voltage **Current Rating Per Characteristic:** 12.00 amperes drain current and 40.00 amperes off-state current, peak **Power Rating Per Characteristic:** 60.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Weapon system essential **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

No

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